

SPW11N80C3

Request a Quote

SPW11N80C3 Information

www.hoj.com	Part Number	SPW11N80C3
	Manufacturer	Infineon Technologies
	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
	Description	MOSFET N-CH 800V 11A TO-247
	Package	TO-247-3
		For the pricing/inventory/lead time, please contact us
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SPW11N80C3 Specifications

Manufacturer Part Number	SPW11N80C3
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	CoolMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	800V
Current - Continuous Drain (Id) @ 25°C	11A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	3.9V @ 680µA
Gate Charge (Qg) (Max) @ Vgs	85nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1600pF @ 100V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	156W (Tc)
Rds On (Max) @ Id, Vgs	450 mOhm @ 7.1A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO247-3
Package / Case	TO-247-3
	Report errors?

SPW11N80C3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

SPW11N80C3 Payment Methods



SPW11N80C3 Shipping Methods



If you have any question about SPW11N80C3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com